

Supplementary Materials

# A Ru-Doped $\text{VTi}_{2.6}\text{O}_{7.2}$ Anode with High Conductivity for Enhanced Sodium Storage

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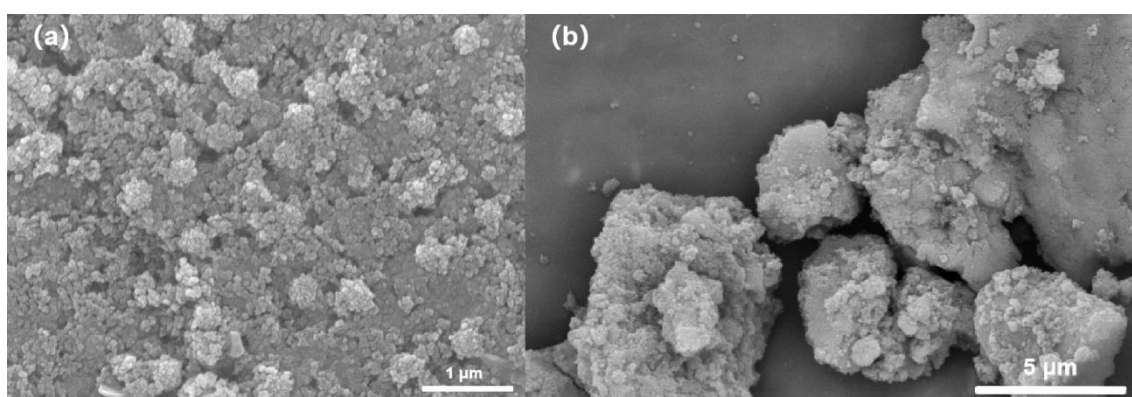


Figure S1. SEM images of (a) Ru-VTO and (b) VTO.

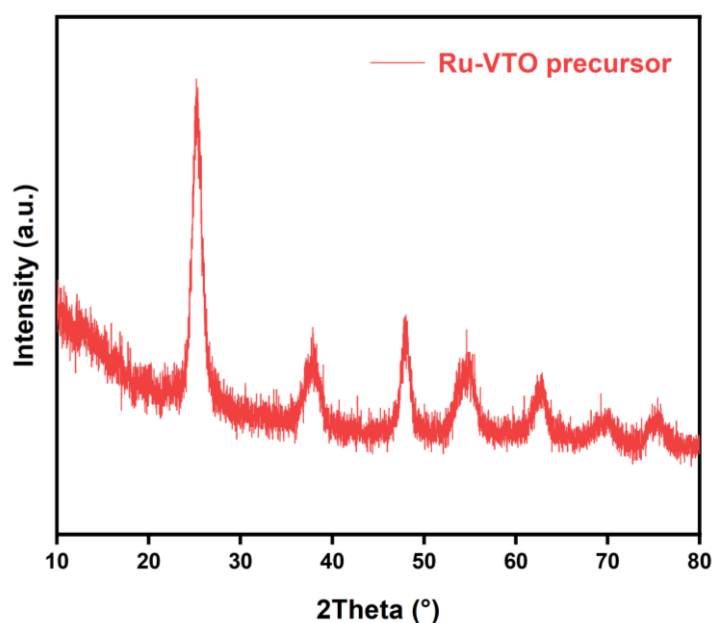
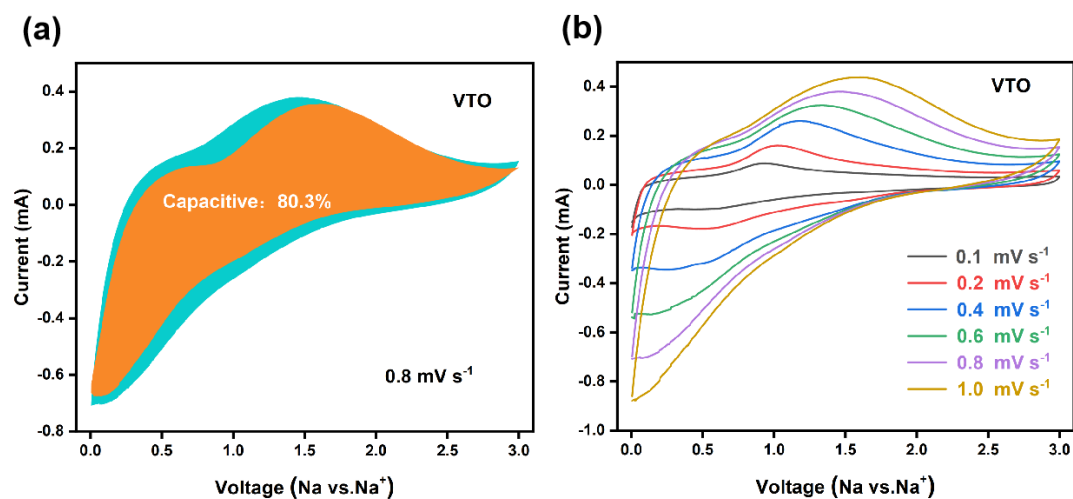
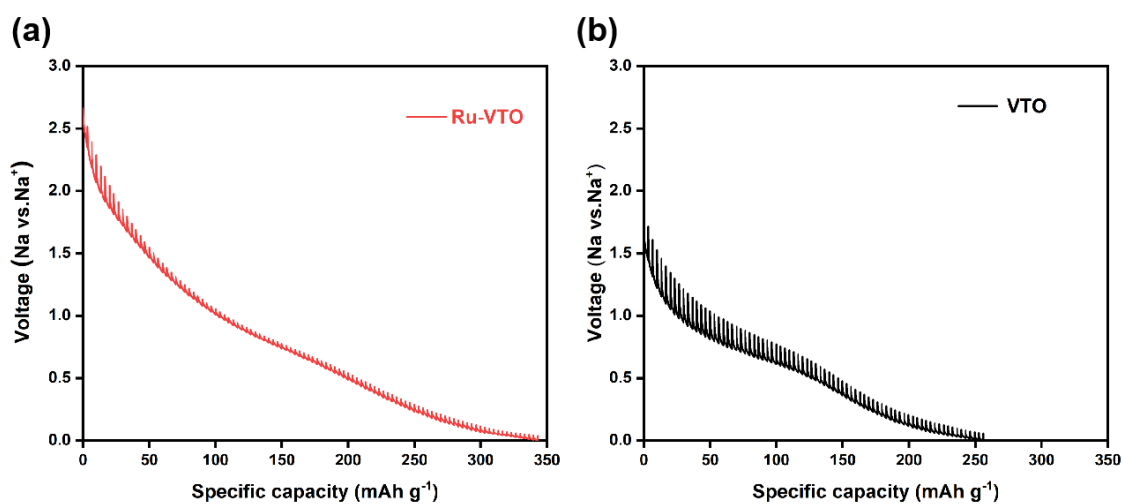


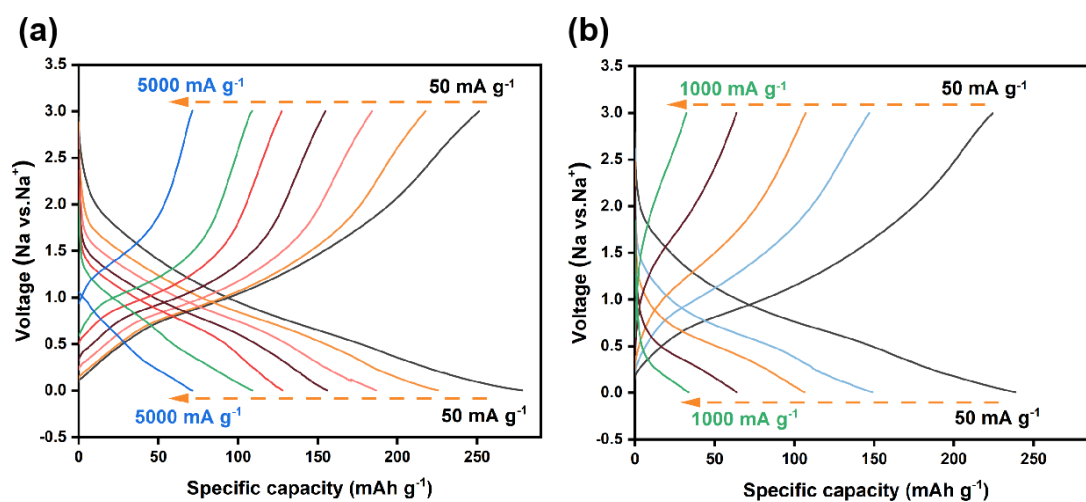
Figure S2. XRD pattern of Ru-VTO precursor.



**Figure S3.** (a) The contribution ratio of the capacitive capacities at  $0.8 \text{ mV s}^{-1}$  for VTO. (b) CV curves of VTO at scan rates range from  $0.1$  to  $1.0 \text{ mV s}^{-1}$ .



**Figure S4.** Potential response during GITT measurements at  $20 \text{ mA g}^{-1}$  for (a) Ru-VTO and (b) VTO.



**Figure S5.** Galvanostatic charge and discharge voltage profiles of (a) Ru-VTO and (b) VTO under different current densities.

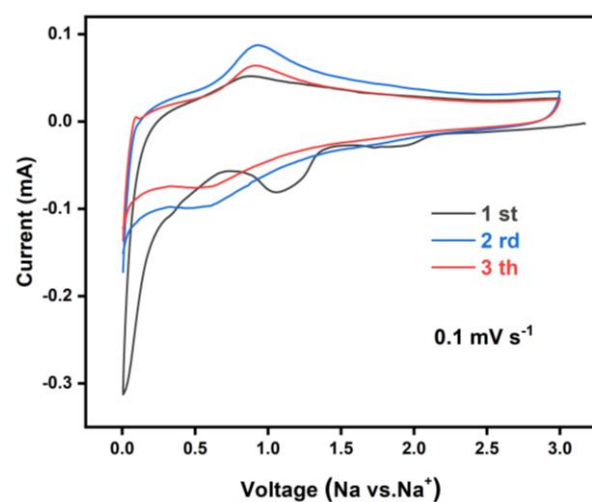


Figure S6. CV test result for the initial three cycles of Ru-VTO at  $0.1 \text{ mV s}^{-1}$ .

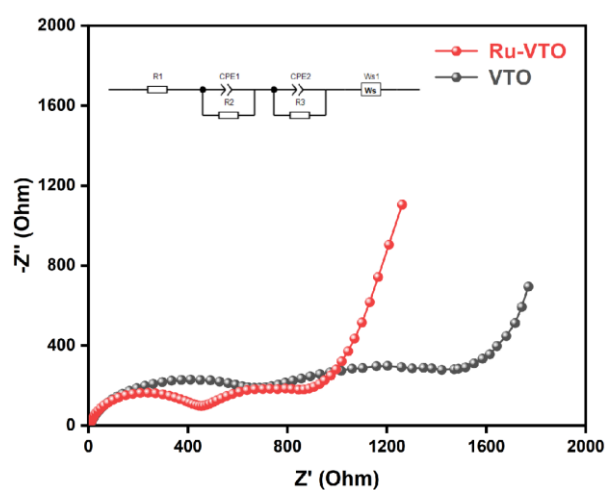


Figure S7. EIS curves of Ru-VTO and VTO.

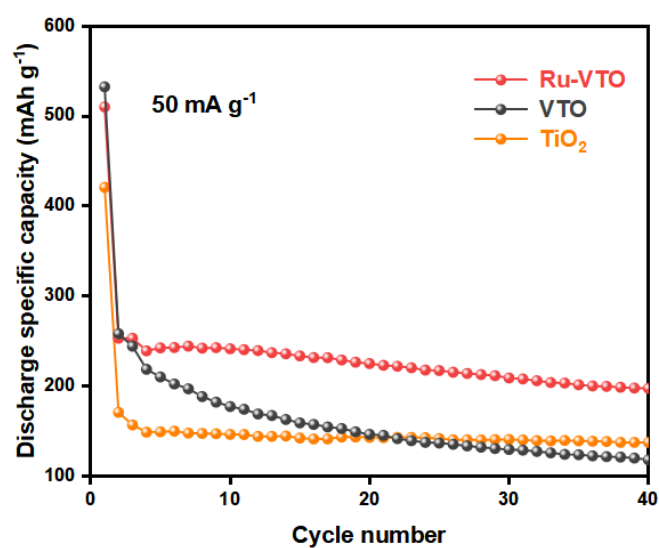


Figure S8. Cycling performance at  $50 \text{ mA g}^{-1}$  for  $\text{TiO}_2$ , VTO and Ru-VTO.

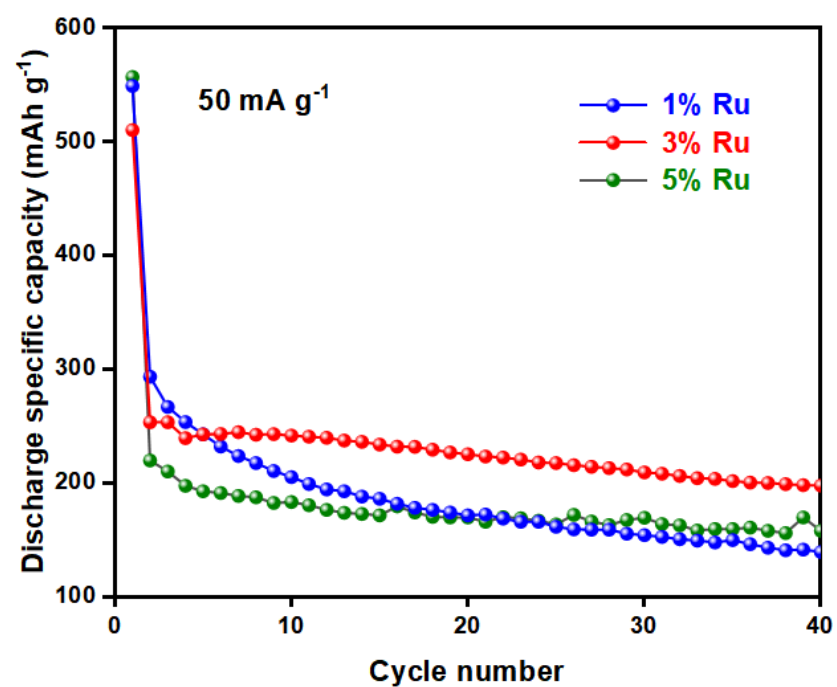


Figure S9. Cycling performance of Ru-doped samples with different concentrations at 50 mA g<sup>-1</sup>.

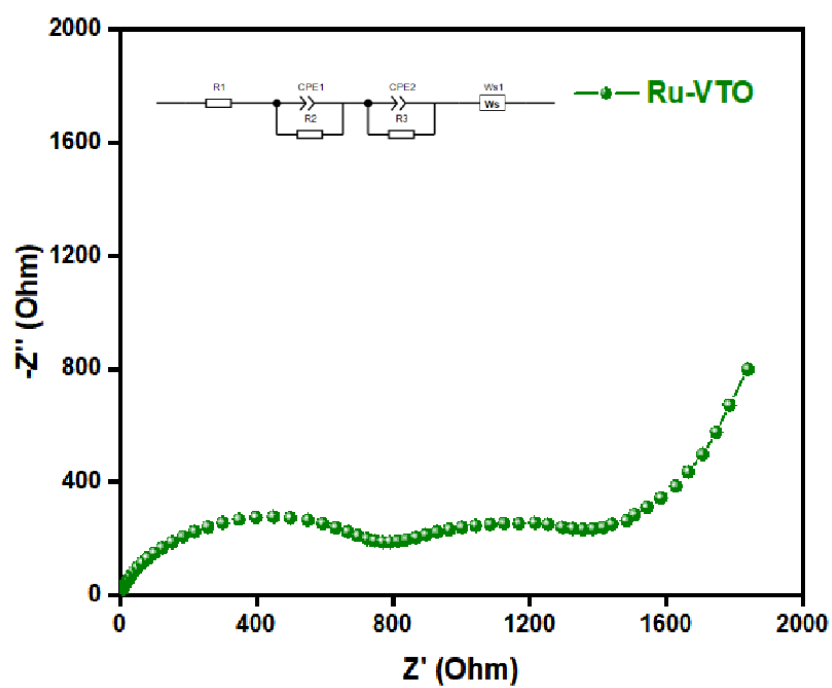


Figure S10. EIS of Ru-VTO after the galvanostatic tests.

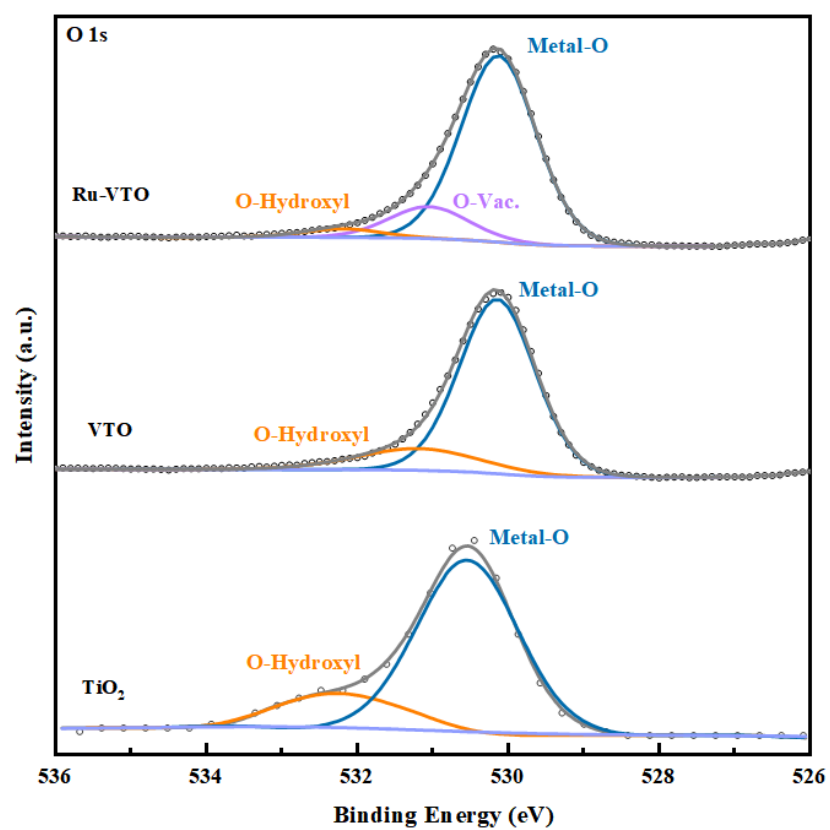


Figure S11. XPS spectra of O 1s for TiO<sub>2</sub>, VTO and Ru-VTO.

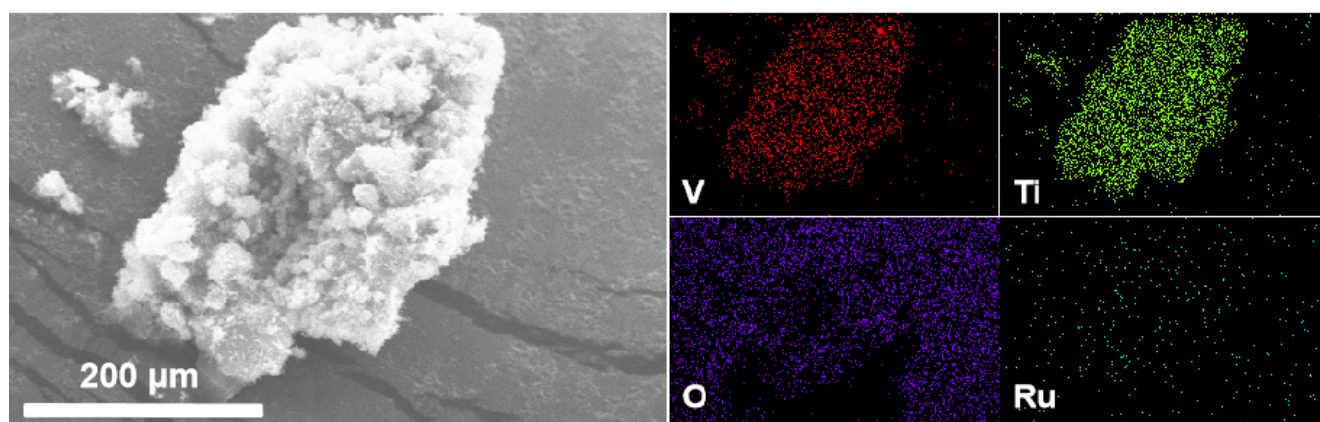
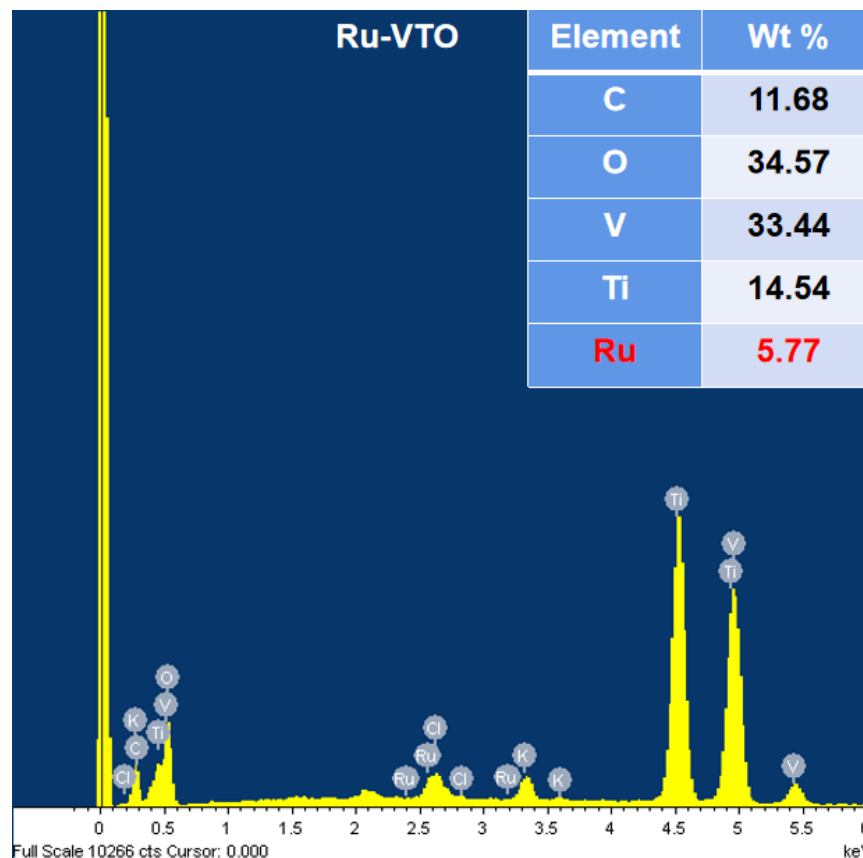


Figure S12. Element mapping of Ru-VTO.



**Figure S13.** The quantitative EDS analysis for Ru-VTO.

The crystallite size of Ru-VTO sample can be calculated according to the following equation:

$$D = \frac{k\lambda}{\beta \cos \theta} \quad (\text{S1})$$

$D$  is the grain size,  $k$ ,  $\lambda$ ,  $\beta$ , and  $\theta$  are Scherrer constant, X-ray wavelength, Diffraction peak half-height width, and Cape Prague respectively. The value of  $k$  is 0.89, and  $\lambda$  is 0.154056, while  $\beta$  and  $\theta$  need to be obtained by XRD profile.

**Table S1.** Elemental content analysis of XPS for Ru-VTO.

Name	Pos.	Area	At. %
V 2p	517	8276.17	8.77
Ti 2p	468	19371.82	21.70
O 1s	531	23666.72	68.00
Ru 3d	281	2930.60	1.54